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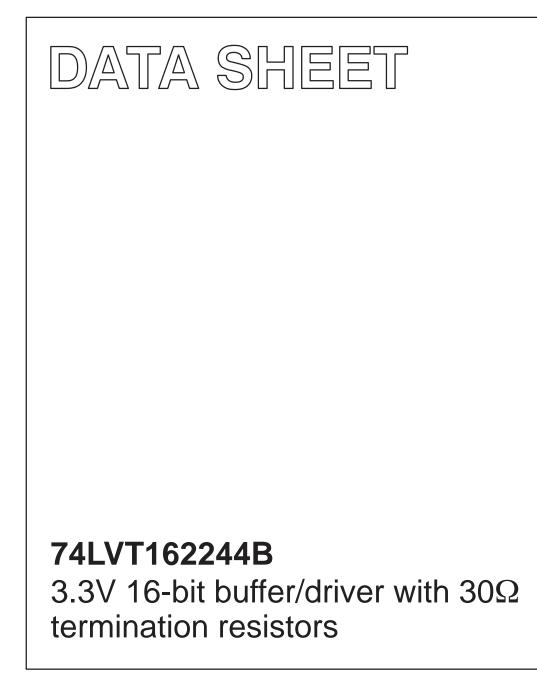
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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS



Product specification Supersedes data of 1998 Feb 19 IC23 Data Handbook

1998 Oct 07



Philips Semiconductors

74LVT162244B

FEATURES

- 16-bit bus interface
- 3-State buffers
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Outputs include series resistance of 30Ω making external terminating resistors unnecessary
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model
- Same part as 74LVT16244B-1

QUICK REFERENCE DATA

DESCRIPTION

The 74LVT162244B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

The 74LVT162244B is designed with 30Ω series resistance in both the High and Low states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

This device is a 16-bit buffer and line driver featuring non-inverting 3-State bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

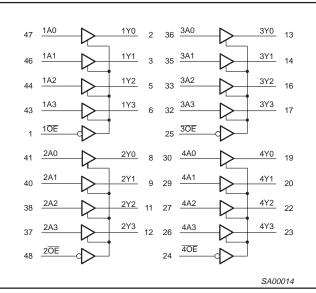
The 74LVT162244B is the same as the 74LVT16244B-1. The part number has been changed to reflect industry standards.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	C _L = 50pF; V _{CC} = 3.3V	2.8	ns
C _{IN}	Input capacitance nOE	$V_{I} = 0V \text{ or } 3.0V$	3	pF
C _{OUT}	Output capacitance	Outputs disabled; $V_0 = 0V$ or 3.0V	9	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	70	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT162244B DL	VT162244B DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74LVT162244B DGG	VT162244B DGG	SOT362-1

LOGIC SYMBOL



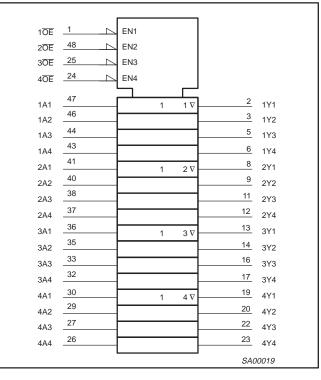
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 - 1A3, 2A0 - 2A3, 3A0 - 3A3, 4A0 - 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs
1, 48 25, 24	10E, 20E, 30E, 40E	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

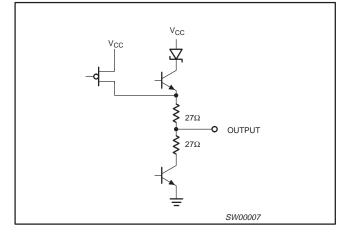
Product specification

74LVT162244B

LOGIC SYMBOL (IEEE/IEC)



SCHEMATIC OF EACH OUTPUT



PIN CONFIGURATION

1 0 E		48 2 0E
1Y0	2	47 1A0
1Y1	3	46 1A1
GND	4	45 GND
1Y2	5	44 1A2
1Y3	6	43 1A3
VCC	7	42 V _{CC}
2Y0	8	41 2A0
2Y1	9	40 2A1
GND	10	39 GND
2Y2	11	38 2A2
2Y3	12	37 2A3
3Y0	13	36 3A0
3Y1	14	35 3A1
GND	15	34 GND
3Y2	16	33 3A2
3Y4	17	32 3A3
VCC	18	31 V _{CC}
4Y0	19	30 4A0
4Y1	20	29 4A1
GND	21	28 GND
4Y2	22	27 4A2
4Y3	23	26 4A3
40E	24	25 3 0E
	·	SA00013
		0/1000/10

FUNCTION TABLE

INP	OUTPUTS	
nOE	nAx	nYx
L	L	L
L	н	н
н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High Impedance "off" state

74LVT162244B

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER CONDITIONS		RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in Low state	128	
I _{OUT} DC output current	Output in High state	-64	- mA	
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2.

The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWBOL	FARAMETER	MIN	МАХ	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Input voltage		0.8	V
I _{ОН}	High-level output current		-12	mA
I _{OL}	Low-level output current		12	mA
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

Product specification

74LVT162244B

DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	-40°C to	+85°C	UNIT
				MIN	TYP ¹	МАХ	1
VIK	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA				-1.2	
V _{OH}	High-level output voltage	V _{CC} = 3.0V; I _{OH} = -12mA		2.0			V
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 12mA				0.8	1
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$	Control pins		0.1	±1.0	
		$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$			0.4	10	1.
II.	Input leakage current	$V_{CC} = 3.6V; V_I = V_{CC}$			0.1	1	μA
		$V_{CC} = 3.6V; V_{I} = 0$	Data pins ⁴		-0.4	-5	
I _{OFF}	Output off current	$V_{CC} = 0V; V_1 \text{ or } V_0 = 0 \text{ to } 4.5V$	$V_{CC} = 0V; V_1 \text{ or } V_0 = 0 \text{ to } 4.5V$		0.1	±100	μA
		$V_{CC} = 3V; V_1 = 0.8V$		75	135		
I _{HOLD}	Bus Hold current A inputs ⁶	$V_{CC} = 3V; V_1 = 2.0V$		-75	-135		μA
		$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			1
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V			50	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ or V_{CC} ; $OE/OE = Don't$ care			1	±100	μΑ
I _{OZH}	3-State output High current	$V_{CC} = 3.6$ V; $V_{O} = 3.0$ V; $V_{I} = V_{IL}$ or V_{IH}			0.5	5	μΑ
I _{OZL}	3-State output Low current	V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} or V_{IH}			0.5	-5	μΑ
I _{CCH}		V_{CC} = 3.6V; Outputs High, V_{I} = GND or	V _{CC,} I _{O =} 0		0.07	0.12	
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V_{I} = GND or V	/ _{CC,} I _{O =} 0		4.0	6.0	mA
I _{CCZ}	1	V_{CC} = 3.6V; Outputs Disabled; V_I = GND or V_{CC} , $I_O = 0^5$			0.07	0.12	
ΔI_{CC}	Additional supply current per input pin ²	$V_{CC} = 3V$ to 3.6V; One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	И,		0.1	0.2	mA

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND 3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2V$ to $V_{CC} = 3.3V \pm 0.3V$ a transition time of 100μ sec is permitted. This parameter is valid for $T_{amb} = 25^{\circ}C$ only. 4. Unused pins at V_{CC} or GND.

5. I_{CCZ} is measured with outputs pulled to V_{CC} or GND.

6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to $+85^{\circ}C$.

SYMBOL	PARAMETER	WAVEFORM	V _C	c = 3.3V ±0	.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	0.5 0.5	2.8 2.5	4.2 4.2	5.0 5.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 1.0	3.5 3.1	5.5 5.5	7.0 6.5	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.0 1.0	3.6 3.1	5.5 5.5	6.0 6.0	ns

NOTE:

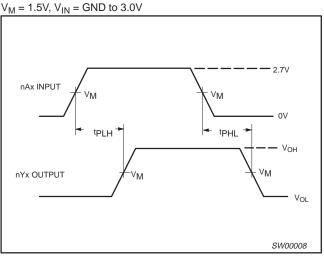
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

SW00003

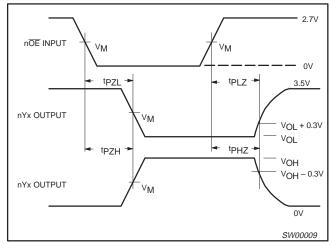
3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

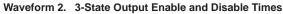
74LVT162244B

AC WAVEFORMS



Waveform 1. Input (nAx) to Output (nYx) Propagation Delays

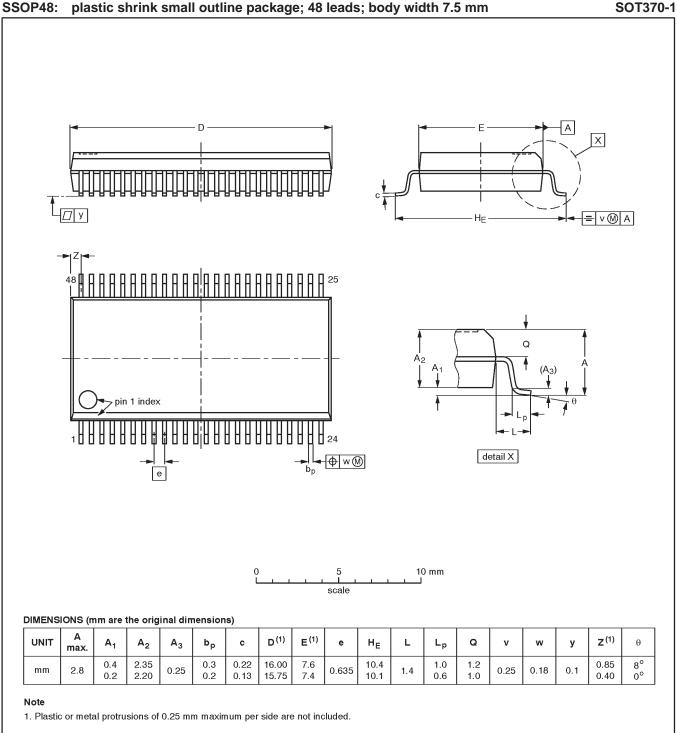




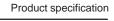
TEST CIRCUIT AND WAVEFORMS 6V VCC AMP (V) tw 90% 90% • OPEN NEGATIVE ٧M V_N PULSE GND 10% 10% VIN VOUT RL 0V PULSE D.U.T. 0 0 t_{THL} (t_F) tTLH (tR) GENERATOR tTLH (tR) RT Rı tTHL (tF) AMP (V) 90% 90% POSITIVE ٧M ٧м PULSE **Test Circuit for 3-State Outputs** 10% 10% 0V tw SWITCH POSITION V_M = 1.5V Input Pulse Definition TEST SWITCH GND t_{PHZ}/t_{PZH} 6V t_{PLZ}/t_{PZL} open t_{PLH}/t_{PHL} **INPUT PULSE REQUIREMENTS** DEFINITIONS FAMILY R_L = Load resistor; see AC CHARACTERISTICS for value. Amplitude Rep. Rate t_F t_R tw C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value. 2.7V 74LVT16 ≤10MHz 500ns ≤2.5ns ≤2.5ns

 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

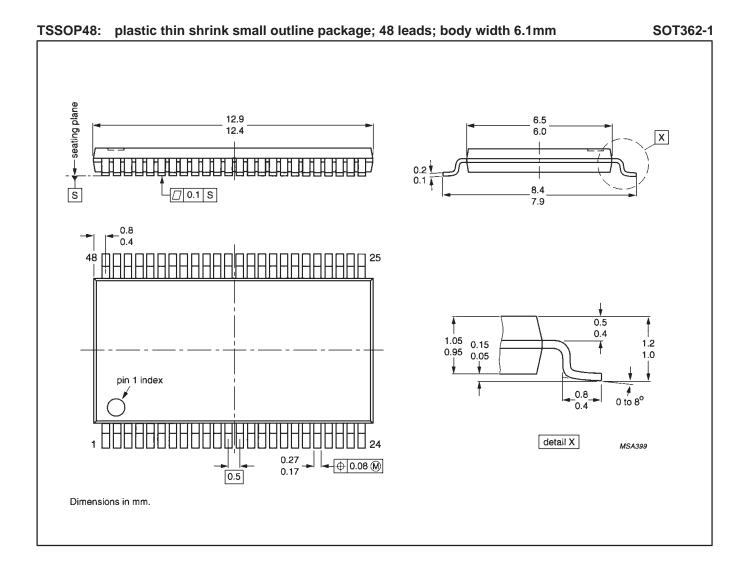
74LVT162244B



OUTLINE	REFERENCES		REFERENCES		REFERENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE		
SOT370-1		MO-118AA				-93-11-02 95-02-04		



74LVT162244B



74LVT162244B

NOTES

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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